NSN 5961-01-575-3147

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Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
500.0 emitter to base voltage, instantaneous not applicable
Power Rating Per Characteristic:
280.0 watts off-state power dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 inlet swivel per square yard
Special Features:
Mosfet
Terminal Type And Quantity:
3 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0